SQJQ141EL

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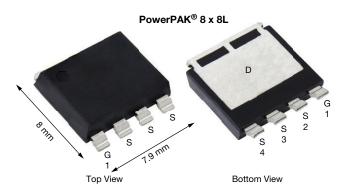
Vishay Siliconix

AUTOMOTIVE

RoHS

COMPLIANT

Automotive P-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY	
V _{DS} (V)	-40
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 V$	0.0020
I _D (A)	-390
Configuration	Single
Package	PowerPAK 8 x 8L

FEATURES

- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Thin 1.6 mm package
- Very low thermal resistance
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

P-Channel MOSFET



ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unles	s otherwise noted	l)	
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	-40	v
Gate-source voltage	V _{GS}	± 20	v	
Continuous drain current	T _C = 25 °C	I-	-390	
Continuous drain current	T _C = 125 °C	Ι _D	-226	
Continuous source current (diode conduction)	ا _S	545	А	
Pulsed drain current ^b		I _{DM}	-489	
Single pulse avalanche current	gle pulse avalanche current		66	
Single pulse avalanche energy		E _{AS}	218	mJ
Maximum power dissipation	$T_{\rm C} = 25 ^{\circ}{\rm C}$		600	w
	T _C = 125 °C	P _D	200	~~~~
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C
Soldering recommendations (peak temperature)		260		

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^c	R _{thJA}	44	°C/W
Junction-to-case (drain)		R _{thJC}	0.25	0/10

Notes

a. Package limited

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

c. When mounted on 1" square PCB (FR4 material)

d. See solder profile (<u>www.vishay.com/doc?73257</u>). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

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SPECIFICATIONS ($T_C = 25 \circ C$, unless oth	erwise noted)						
PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT		
Static								
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$		-40	-	-	v	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μΑ	-1.5	-2	-2.5	v	
Gate-source leakage	I _{GSS}	V _{DS} =	$= 0 \text{ V}, \text{ V}_{\text{GS}} = \pm 20 \text{ V}$	-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = -40 V	-	-	1		
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V_{DS} = -40 V, T_{J} = 125 °C	-	-	200	μA	
		$V_{GS} = 0 V$	$V_{DS} = -40 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	330		
On-state drain current ^a	I _{D(on)}	$V_{GS} = -10 V$	$V_{DS} \ge -5 V$	-100	-	-	Α	
		$V_{GS} = -4.5 V$	I _D = 8 A	-	0.0020	0.0029		
Drain-source on-state resistance ^a	Р	$V_{GS} = -10 V$	I _D = -10 A	-	0.0014	0.0020	Ω	
	R _{DS(on)}	$V_{GS} = -10 V$	I _D = -10 A, T _J = 125 °C	-	-	0.0035	52	
		V _{GS} = 10 V	I _D = -10 A, T _J = 175 °C	-	-	0.0040	1	
Forward transconductance ^b	g fs	gfs V _{DS} = -15 V, I _D = -50 A - 180 - 5 C _{iss} - 44 421 62 190 -		S				
Dynamic ^b								
Input capacitance	C _{iss}			-	44 421	62 190		
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	1633	2287	pF	
Reverse transfer capacitance	C _{rss}			-	1476	2067		
Total gate charge ^c	Qg			-	487	731		
Gate-source charge ^c	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = -20 \text{ V}, \text{ I}_{D} = -30 \text{ A}$	-	89	-	nC	
Gate-drain charge ^c	Q _{gd}			-	82	-		
Gate resistance	Rg		f = 1 MHz	1.1	2.2	3.3	Ω	
Turn-on delay time ^c	t _{d(on)}			-	22	33		
Rise time ^c	tr	V _{DD} =	-20 V, R _L = 0.67 Ω	-	30	45		
Turn-off delay time ^c	t _{d(off)}	I _D ≅ -30 A,	V_{GEN} = -10 V, R_g = 1 Ω	-	196	294	ns	
Fall time ^c	t _f			-	64	96		
Source-Drain Diode Ratings and Cha	racteristics ^b							
	t _a			-	21	-		
Reverse recovery time	t _b			-	19	-	ns	
	t _{rr}	V _{DD} =	-32 V, I _{FM} = -20 A,	-	40	80		
Reverse recovery charge	Q _{rr}		/dt = 100 A/µs	-	42	84	nC	
Reverse recovery current	I _{RM}]		-	-	2.0	Α	
Pulsed current ^a	I _{SM}	1		-	-	1100	Α	
Forward voltage	V _{SD}		= -50 A, V _{GS} = 0	-	-0.8	-1.1	V	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

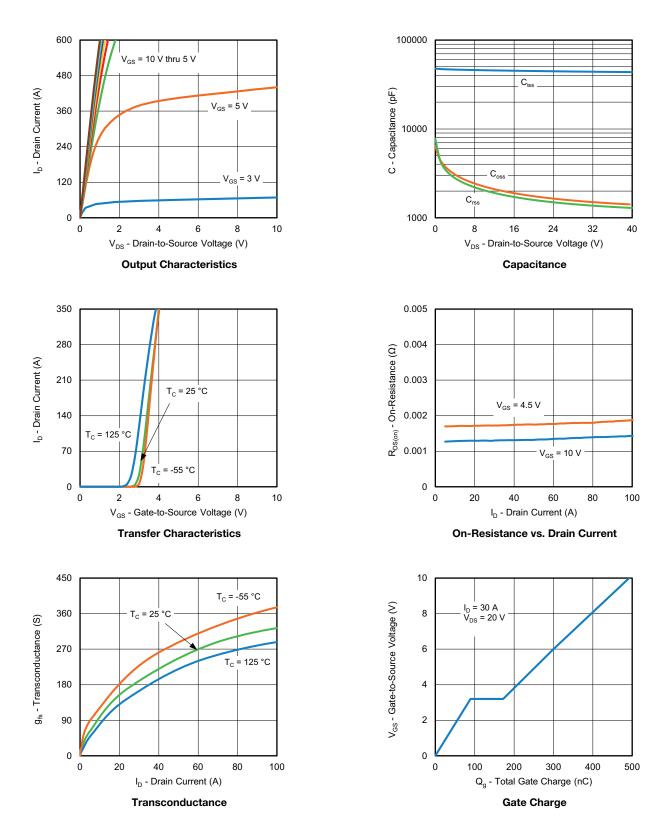
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



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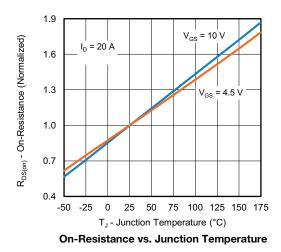
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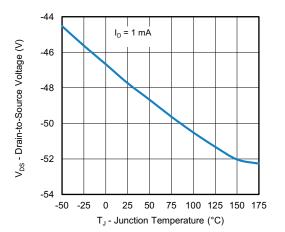


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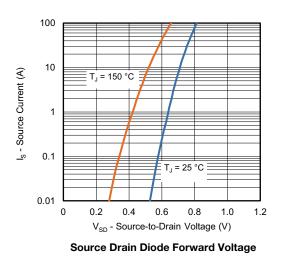
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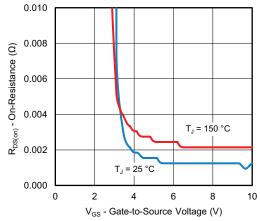
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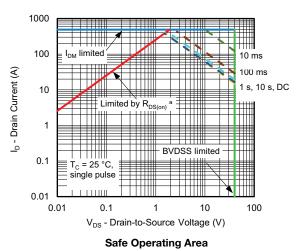


Drain Source Breakdown vs. Junction Temperature

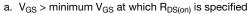


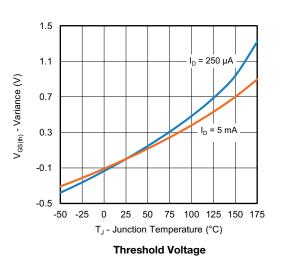


On-Resistance vs. Gate-to-Source Voltage









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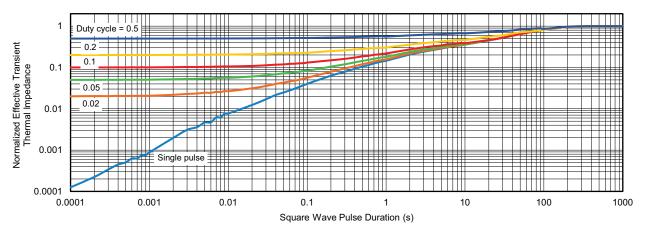
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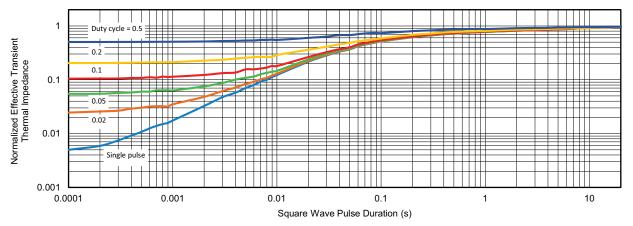
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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



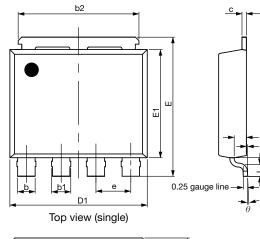
Normalized Thermal Transient Impedance, Junction-to-Case

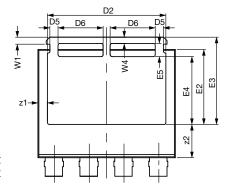
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PowerPAK[®] 8 x 8L BWL Case Outline 2

A1





Bottom view (single)

1					1	- 4	L
F	-				⇒	∢	
							1
~			 L	 			-

DIM.						
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
А	1.50	1.60	1.70	0.059	0.063	0.067
A1	0.00	-	0.127	0.000	-	0.005
A2	0.655	0.705	0.755	0.026	0.028	0.030
b	0.92	1.00	1.08	0.036	0.039	0.043
b1	1.02	1.10	1.18	0.040	0.043	0.046
b2	6.84	6.94	7.04	0.269	0.273	0.277
С	0.20	0.25	0.30	0.008	0.010	0.012
D1	7.80	7.90	8.00	0.307	0.311	0.315
D2	6.70	6.80	6.90	0.264	0.268	0.272
D5	0.37	0.47	0.57	0.015	0.019	0.022
D6	2.49	2.59	2.69	0.098	0.102	0.106
е	1.97	2.00	2.03	0.078	0.079	0.080
E	7.90	8.00	8.10	0.311	0.315	0.319
E1	6.12	6.22	6.32	0.241	0.245	0.249
E2	4.21	4.31	4.41	0.166	0.170	0.174
E3 4.92		5.02	5.12	0.194	0.198	0.202
E4	3.80	3.90	4.00	0.150	0.154	0.157
E5	0.65	0.75	0.85	0.026	0.030	0.033
L	0.61	0.68	0.75	0.024	0.027	0.030
L1	1.00	1.07	1.15	0.039	0.042	0.045
W1	0.30	0.40	0.50	0.012	0.016	0.020
W4	0.32	0.37	0.42	0.013	0.015	0.017
z1	0.45	0.55	0.65	0.018	0.022	0.026
z2	1.81	1.91	2.01	0.071	0.075	0.079
θ	0°	-	5°	0°	-	5°

Note

Millimeter will govern

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